Drag in Paired Electron-Hole Layers

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We investigate transresistance effects in electron-hole double-layer systems with a superfluid electron-hole condensate. Our theory is based on the use of a minimum dissipation premise to fix the current carried by the condensate. We find that the drag resistance jumps discontinuously at the condensation temperature and diverges as the temperature approaches zero.

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The possibility of realizing a superfluid condensate in a system composed of spatially separated layers of electrons and holes was proposed some time ago [1]. Only recently, however, has it become feasible [2-5] to produce systems where the electrons and holes are close enough together to interact strongly and at the same time sufficiently isolated to strongly inhibit optical recombination. Hopes that a superfluid electron-hole condensate might occur are supported by theoretical work in the strong magnetic field limit [6,7] where some simplifications occur and the conclusion can be established with greater confidence. In this Letter we present a theory of transresistivity coefficients, which relate electric fields in one layer to currents flowing in the opposite layer, for the case of an electron-hole double-layer (EHDL) system with a superfluid electronhole condensate. We conclude that the measurement of these transport coefficients could provide an unambiguous experimental indication of the existence of the condensate. Interest in transconductance coefficients for nearby electron and hole layers [8] has increased lately [9] with the advent of accurate experimental measurements [4,10]. When no condensate is present, the transresistivity is typically [10] several orders of magnitude smaller than the isolated layer resistivity. In our theory, the transresistivity jumps to a value comparable to the isolated layer resistivity as soon as the condensate forms, it continues to increase with decreasing temperature T, and it diverges as

The starting point for our theory is a minimum dissipation [11] premise which we use to fix the pair momentum of the condensed electron-hole pairs in the nonequilibrium current carrying state of the EHDL system. Using a matrix notation for the layer indices (e for electrons, h for holes) we partition the total current density into a superfluid portion [$\mathbf{j}_s = (j_{sh}, j_{se})$] carried by the condensate and a normal portion [$\mathbf{j}_n = (j_{nh}, j_{ne})$] carried by the quasiparticles:

$$\mathbf{j} = \mathbf{j}_s + \mathbf{j}_n, \tag{1}$$

where the superfluid portion is proportional to the pairing-momentum P. (\vec{P} will be directed along the direction of

current flow.) Since it represents the flow of oppositely charged bound pairs, $\mathbf{j}_s = (Pen_{\text{pair}}/m_{\text{pair}})(1,-1)$ where $n_{\text{pair}}/m_{\text{pair}}$ is defined by this equation. The physical situations of interest to us will include ones in which the sum of electron and hole currents is not zero so that \mathbf{j}_n cannot be zero. A quasiparticle current will be generated if electric fields which drive the quasiparticles from equilibrium with the condensate are present in the electron and hole layers. In linear response

$$\mathbf{j}_n = \boldsymbol{\sigma}^{\mathrm{qp}} \mathbf{E} \,. \tag{2}$$

(Expressions for $n_{\rm pair}/m_{\rm pair}$ and the quasiparticle transconductivity matrix $\sigma^{\rm qp}$ based on a microscopic theory will be derived below.) A quasiparticle current flowing in the presence of electric fields will dissipate energy at a rate per unit area given by the Joule heating expression:

$$W(P) = \mathbf{j}_n \cdot \mathbf{E} = [\mathbf{j} - Pen_{\text{pair}}/m_{\text{pair}}(1, -1)] \cdot \boldsymbol{\rho}^{\text{qp}}$$
$$\cdot [\mathbf{j} - Pen_{\text{pair}}/m_{\text{pair}}(1, -1)], \quad (3)$$

where ρ^{qp} , the quasiparticle transresistivity matrix, is the inverse of the quasiparticle transconductivity matrix. The pairing momentum of the condensate in the nonequilibrium current carrying state will be the one which allows the prescribed currents to flow through the system with minimum dissipation. Applying this condition we find a surprisingly simple result:

$$\mathbf{i}_{s} \cdot \mathbf{E} = 0. \tag{4}$$

The electric fields in electron and hole layers are identical independent of the microscopic transresistivity matrix and the prescribed currents.

Explicit expressions for \mathbf{j}_s , \mathbf{j}_n , and \mathbf{E} can be obtained by combining Eqs. (1), (2), and (4). We find that for prescribed current $\mathbf{j} = (j_h, j_e)$,

$$j_{sh} = -j_{se} = \frac{(\rho_{hh}^{qp} - \rho_{eh}^{qp})j_h - (\rho_{ee}^{qp} - \rho_{eh}^{qp})j_e}{\rho_{ee}^{qp} + \rho_{hh}^{qp} - 2\rho_{eh}^{qp}}, \quad (5)$$

$$\mathbf{j}_n = \mathbf{j} - \mathbf{j}_s$$
, and

$$E_h = E_e = \rho_{cd}(j_e + j_h).$$
 (6)

In Eq. (6) ρ_{cd} , which we will refer to as the condensate drag resistivity, is related to the components of the quasi-particle transresistivity and transconductivity matrices by

$$\rho_{cd} = \frac{\rho_{ee}^{qp} \rho_{hh}^{qp} - (\rho_{eh}^{qp})^{2}}{\rho_{ee}^{qp} + \rho_{hh}^{qp} - 2\rho_{eh}^{qp}}$$

$$= \frac{1}{\sigma_{ee}^{qp} + \sigma_{hh}^{qp} + 2\sigma_{eh}^{qp}}.$$
 (7)

Our conclusions thus far do not depend on the nature of the microscopic mechanism of superfluidity. We now turn our attention to the evaluation of ρ_{cd} in a specific microscopic model. We will restrict our attention to the case where the particle densities in electron and hole layers are identical $(n_e = n_h = n)$ and use the BCS mean-field theory [12] to describe the pairing. approach is qualitatively correct in the regime of high electron and hole densities, which is most accessible to experiments [13]. We will be able to express our results in terms of the solution to the mean-field gap equations at P = 0. Taking the effective attractive interaction V [14] which enters the BCS equations to be independent of momentum, the gap equations differ from their textbook counterparts [12,15] only in that the electron and hole masses $(m_e$ and $m_h)$ are not equal. The quasiparticle energies are given by $(\hbar = 1)$

$$E_{0k} = E_k + \eta_k,$$

 $E_{1k} = E_k - \eta_k,$ (8)

where $E_k = (\epsilon_k^2 + \Delta^2)^{1/2}$, $\epsilon_k = (k^2 - k_F^2)/2m_+$, $\eta_k = (k^2 - k_F^2)/2m_-$, $2m_{\pm}^{-1} = m_e^{-1} \pm m_h^{-1}$, and $k_F = (2\pi n)^{1/2}$ is the Fermi momentum. The gap Δ is determined by solving the gap equation:

$$\frac{1}{\lambda} = \int_0^{\omega_c} d\epsilon_k \frac{1}{\sqrt{\Delta^2 + \epsilon_k^2}} [1 - f(E_{0k}) - f(E_{1k})].$$

In Eq. (9) $\lambda = N(0)V$ [N(0) is the density of states of free fermions of mass m_+ and density n] is the usual dimensionless coupling constant [12,15] of BCS theory, $f(E) = [\exp(E/k_BT) + 1]^{-1}$, and ω_c is the cutoff for the attractive interaction.

The microscopic calculations, which are somewhat lengthy, are similar to common applications of BCS theory for superconductivity in metals [12,15]. The main steps of this calculation are sketched and the principal results are given below. We first calculate $n_{\rm pair}/m_{\rm pair}$ by evaluating the electron and hole currents to first order in the pairing momentum P when the quasiparticles are in equilibrium with the condensate. For $m_e = m_h$ this calculation is identical to the calculation of the superfluid density which determines the penetration depth of a

superconductor. We find that

$$\frac{n_{\text{pair}}}{m_{\text{pair}}} = \frac{n_e - n_{ne}}{m_e} = \frac{n_h - n_{nh}}{m_h}$$
. (10)

The equivalence of the two forms for the right hand side of Eq. (10) provides microscopic confirmation of the expectation, used in our minimum dissipation analysis, that the current carried by the electron-hole condensate is equal and opposite in electron and hole layers. In Eq. (10) the electron "normal" density n_{ne} is given by

$$n_{ne} = -\frac{1}{A} \sum_{k} \frac{k^{2}}{2m_{+}} \left[u_{k}^{2} f'(E_{0k}) + v_{k}^{2} f'(E_{1k}) \right]$$
$$-\frac{1}{A} \sum_{k} \frac{k^{2}}{2m_{-}} \frac{\epsilon_{k}}{E_{k}} \left[u_{k}^{2} f'(E_{0k}) - v_{k}^{2} f'(E_{1k}) \right]$$
$$-\frac{1}{A} \sum_{k} \frac{k^{2}}{4m_{-}} \frac{\Delta^{2}}{E_{k}^{2}} \left[f(E_{0k}) + f(E_{1k}) - 1 \right], \quad (11)$$

where $u_k^2 = (1 + \epsilon_k/E_k)/2$, $v_k^2 = (1 - \epsilon_k/E_k)/2$, and A is the area of the layer. The normal hole density n_{nh} is obtained by interchanging the indices e and h, i.e., $E_{0k} \leftrightarrow E_{1k}$ and $m_- \to -m_-$ in the above formula.

We have evaluated the quasiparticle transconductivity in the paired state in a single-loop approximation using the Nambu-Gorkov Green's function formalism. After some standard manipulations [16] this approximation leads to

$$\sigma_{ij}^{qp} = \frac{1}{A} \sum_{\vec{p}} \frac{\pi p^2}{2m_i m_j} \int_{-\infty}^{\infty} f'(\omega) A_{ij}^2(\vec{p}, \omega) d\omega , \quad (12)$$

where i and j are layer indices,

$$\mathbf{A}(\vec{p},\omega) \equiv -\frac{1}{\pi} \operatorname{Im} \mathbf{G}(\vec{p},\omega + i\delta), \qquad (13)$$

and **G** is the Nambu-Gorkov matrix Green's function. In the absence of disorder we have

$$\mathbf{G}_{(0)}(\vec{p},\omega+i\delta) = \frac{(\omega-\eta_p)\hat{1}+\epsilon_p\hat{\tau}_3+\Delta\hat{\tau}_1}{(\omega-E_{0p}+i\delta)(\omega+E_{1p}+i\delta)},$$
(14)

where the τ 's are Pauli matrices. To model disorder we have included a Born approximation [16] self-energy correction $\Sigma(\vec{p},\omega)$ to the Nambu-Gorkov Green's function: $\mathbf{G}^{-1}(\vec{p},\omega) = \mathbf{G}_{(0)}^{-1}(\vec{p},\omega) - \Sigma(\vec{p},\omega)$. Assuming zero correlation length for the disorder potential in each layer and no correlation between the disorder in electron and hole layers a lengthy series of algebraic manipulations allows the quasiparticle transconductivity to be expressed in terms of the normal state scattering times for electron and hole layers τ_{ne} and τ_{nh} . We find that

$$\frac{\sigma_{hh}^{qp}}{\sigma_0} = \frac{(1+y)^2}{2\alpha} \int_0^\infty d\epsilon_k \left[\frac{u_k^4 \tilde{\tau}_{0k}}{\cosh^2(E_{0k}/2k_B T)} + \frac{v_k^4 \tilde{\tau}_{1k}}{\cosh^2(E_{1k}/2k_B T)} \right], \tag{15a}$$

$$\frac{\sigma_{ee}^{qp}}{\sigma_0} = \frac{(1-y)^2}{2\alpha} \int_0^\infty d\epsilon_k \left[\frac{v_k^4 \tilde{\tau}_{0k}}{\cosh^2(E_{k0}/2k_B T)} + \frac{u_k^4 \tilde{\tau}_{1k}}{\cosh^2(E_{1k}/2k_B T)} \right], \tag{15b}$$

$$\frac{\sigma_{eh}^{qp}}{\sigma_0} = -\frac{1 - y^2}{2\alpha} \int_0^\infty d\epsilon_k \, u_k^2 v_k^2 \left[\frac{\tilde{\tau}_{0k}}{\cosh^2(E_{0k}/2k_B T)} + \frac{\tilde{\tau}_{1k}}{\cosh^2(E_{1k}/2k_B T)} \right],\tag{15c}$$

where $y \equiv (m_e - m_h)/(m_h + m_e)$, $r \equiv (\tau_{ne} - \tau_{nh})/(\tau_{nh} + \tau_{ne})$, $\alpha = (1 + y)/(1 + r) + (1 - y)/(1 - r)$, $2(\tau_n)^{-1} \equiv \tau_{nh}^{-1} + \tau_{ne}^{-1}$, $\sigma_0 \equiv ne^2 \tau_n \alpha/m_+$, and $\tilde{\tau}_{0k}$ and $\tilde{\tau}_{1k}$ are the energy dependent scattering times which give the lifetimes of the quasiparticle states in units of τ_n :

$$\tilde{\tau}_{0k} = \frac{|\epsilon_k/E_k + y|}{u_k^4(1+y)(1+r) + v_k^4(1-y)(1-r)},$$

$$\tilde{\tau}_{1k} = \frac{|\epsilon_k/E_k - y|}{u_k^4(1-y)(1-r) + v_k^4(1+y)(1+r)}.$$
(16)

In Fig. 1 we show numerical results calculated from the above expressions for the values $m_h/m_e=7.57$, $\tau_{ne}/\tau_{nh}=m_h/m_e$ appropriate to electrons and holes in GaAs, with equal concentrations of impurities in the two layers. (The precise values of the parameters have no qualitative importance.) The drag resistivity $\rho_{cd}\equiv\sigma_{cd}^{-1}$ immediately jumps to a value comparable to the normal state resistivity $(\sim\sigma_0^{-1})$ at T_c and it diverges exponentially as the temperature goes to zero. In this limit the quasiparticle conductivity vanishes because of the small number of thermally excited quasiparticles. Consequently, a larger and larger electric field is required to drive the normal component of the current. We also plot the behavior of the quasiparticle conductivities σ_{ee}^{qp} , σ_{hh}^{qp} , and σ_{eh}^{qp} in the superfluid phase. The quasiparticle transconductivity σ_{eh}^{qp} vanishes as $T \to T_c$ because, in our theory, we include no correlation between the two

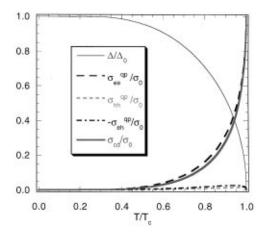


FIG. 1. Ratio of the BCS model condensate drag conductivity $\sigma_{cd} = \sigma_{ee}^{\rm qp} + \sigma_{hh}^{\rm qp} + 2\sigma_{eh}^{\rm qp} = \rho_{cd}^{-1}$ to the normal double-layer conductivity σ_0 as a function of T/T_c for GaAs $(m_h/m_e=7.57 \text{ and } \tau_{ne}/\tau_{nh}=m_h/m_e)$. Also plotted quasiparticle conductivities $\sigma_{ee}^{\rm qp}/\sigma_0$, $\sigma_{hh}^{\rm qp}/\sigma_0$, and $\sigma_{eh}^{\rm qp}/\sigma_0$, and BCS gap Δ in units of its zero temperature value Δ_0 . Qualitatively similar results are obtained for different values of the parameters.

layers other than the one implied by the existence of the electron-hole condensate.

Our microscopic calculations are based on the BCS scenario of the superfluid transition. This is the most likely scenario for electron-hole double layers at densities of experimental interest. At lower densities other routes are possible. For example, one could have exciton pair formation in the normal state, followed by Bose-Einstein condensation at lower temperature. In this scenario, the transresistivity would be large even in the normal state, due to the strong electron-hole correlation. In the superfluid state Eq. (6) would still hold, following merely from the possibility of dissipation-free conduction. Arguments similar to those presented earlier lead us to conclude that even in this case the transresistivity would increase discontinuously at the condensation temperature, although the size of the jump could be considerably smaller than in the high density case.

In the two-dimensional electron-hole layers, considered in this Letter, the superfluid transition is expected to be of the Kosterlitz-Thouless type. This means that our microscopic theory may require quantitative correction in a region near the transition temperature where fluctuations are important. In particular, the "jump" in the transresistivity could be distributed over a finite temperature range. At lower temperatures our macroscopic analysis shows that the qualitative behavior of the transresistivity is completely independent of microscopic details. We conclude that transresistance measurements should provide a fool-proof test for the presence of a superfluid condensate.

In closing we note that the analysis presented here is based on the linear approximation for the response of quasiparticles to an electric field. This approximation is justified for sufficiently weak electric fields, i.e., fields satisfying the condition $eE\xi \ll \Delta$, where ξ is the coherence length. In terms of the current flowing in one layer (with the other layer kept in an open circuit) this condition takes the form [see Eq. (6), with $j_h = 0$] $j_e/j_c \ll \min\{1, \frac{n_n}{n} \frac{v_F \tau}{\xi}\}$, where $j_c = n\hbar/m\xi$ is the thermodynamic critical current, τ is the elastic scattering time of quasiparticles, v_F is the Fermi velocity, and n_n is the "normal fluid" density. Thus, at any finite temperature below T_c , there is a finite range of weak currents in which our linear response approximation is valid. However, the restriction becomes more and more stringent as $T \to T_c$ and $\xi \to \infty$. A theoretical investigation of nonlinear effects remains an interesting problem for the future.

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